

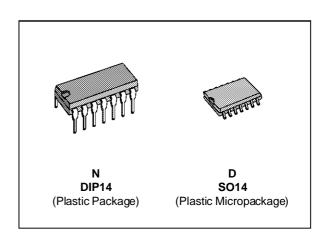
LM148 LM248 - LM348

FOUR UA741 QUAD BIPOLAR OPERATIONAL AMPLIFIERS

- LOW SUPPLY CURRENT: 0.53mA/AMPLIFIER
- CLASS AB OUTPUT STAGE: NO CROSS-OVER DISTORTION
- PIN COMPATIBLE WITH LM124
- LOW INPUT OFFSET VOLTAGE: 1mV
- LOW INPUT OFFSET CURRENT: 2nA
- LOW INPUT BIAS CURRENT: 30nA
- GAIN BANDWIDTH PRODUCT: 1.3MHz
- HIGH DEGREE OF ISOLATION BETWEEN AMPLIFIERS: 120dB
- OVERLOAD PROTECTION FOR INPUTS AND OUTPUTS

where amplifier matching or high packing density is

required.



ORDER CODES

Part Num-	Temperature	Package				
ber	Range	N	D			
LM148	−55°C, +125°C	•	•			
LM248	–40°C, +105°C	•	•			
LM348	LM348 0°C, +70°C		•			
Example: LM348D						

V_C C

Output 3

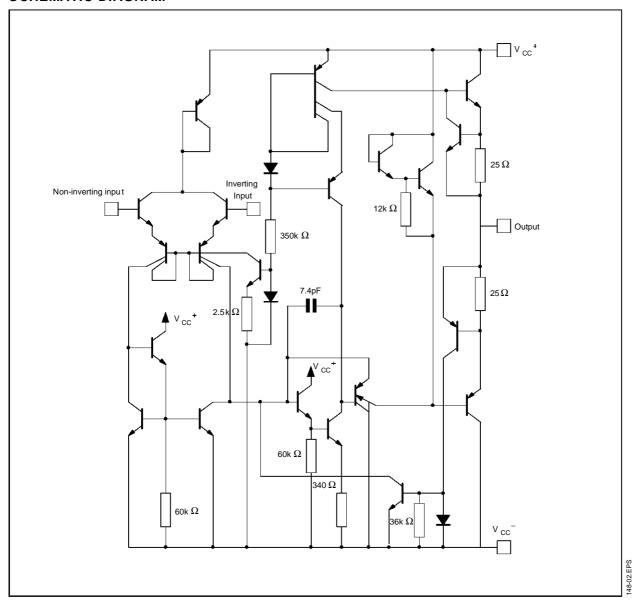
Non-inverting input 3

PIN CONNECTIONS (top view)

DESCRIPTION The LM148 consists of four independent, high gain internally compensated, low power operational amplifiers which have been designed to provide functional characteristics identical to those of the familiar UA741 operational amplifier. In addition the total supply current for all four amplifiers is comparable to the supply current of a single UA741 type op amp. Other features include input offset current and input bias current which are much less than п Non-inverting input 2 5 those of a standard UA741. Also, excellent isolation Inverting input 2 between amplifiers has been achieved by inde-Out put 2 pendently biasing each amplifier and using layout techniques which minimize thermal coupling. The LM148 can be used anywhere multiple UA741 type amplifiers are being used and in applications

April 1995 1/9

SCHEMATIC DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	LM148	LM248	LM348	Unit
Vcc	Supply Voltage	± 22	± 22	± 22	V
V _{id}	Differential Input Voltage	±44	± 44	± 44	V
Vi	Input Voltage (note 1)	± 22	± 22	± 22	V
P _{tot}	Power Dissipation	500	500	500	mW
	Output Short-circuit Duration (note 2)	Infinite			
T _{oper}	Operating Free-air Temperature Range	– 55, + 125	-40, +105	0, +70	°C
T _{stg}	Storage Temperature Range	-65, +150	− 65, + 150	-65, +150	°C

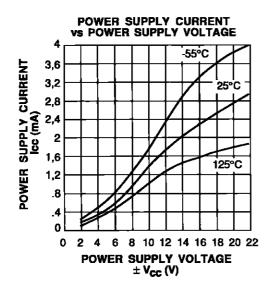
Notes: 1. For supply voltage less than maximum value, the absolute maximum input voltage is equal to the supply voltage.

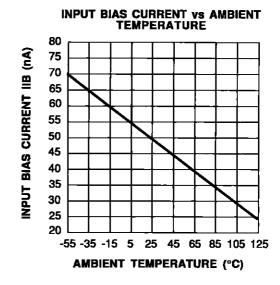
^{2.} Any of the amplifier outputs can be shorted to ground indefinitely; however, more than one should not be simultaneously shorted as the maximum junction temperature will be exceeded.

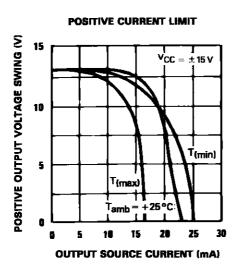
ELECTRICAL CHARACTERISTICS

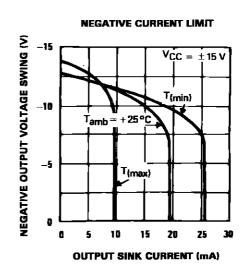
 $V_{CC} = \pm 15V$, $T_{amb} = 25^{\circ}C$ (unless otherwise specified)

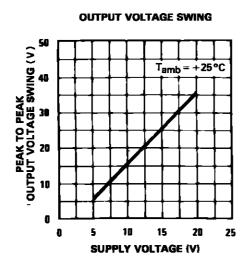
Symbol	Parameter	LM14	LM148 - LM248 - LM348		
Зушьог	Farameter	Min.	Тур.	Max.	Unit
V_{io}	$ \begin{array}{l} \text{Input Offset Voltage } (R_S \leq 10 k\Omega) \\ T_{amb} = 25^{\circ} C \\ T_{min.} \leq T_{amb} \leq T_{max.} \end{array} $		1	5 6	mV
l _{io}			2	25 75	nA
l _{ib}			30	100 300	nA
A_{vd}	Large Signal Voltage Gain ($V_0 = \pm 10V$, $R_L = 2k\Omega$) $T_{amb} = 25^{\circ}C$ $T_{min.} \le T_{amb} \le T_{max.}$	50 25	160		V/mV
SVR	Supply Voltage Rejection Ratio ($R_S \le 10k\Omega$) $T_{amb} = 25^{\circ}C$ $T_{min.} \le T_{amb} \le T_{max.}$	77 77	100		dB
lcc	Supply Current, all Amp, no Load $T_{amb} = 25^{\circ}C$ $T_{min.} \le T_{amb} \le T_{max.}$		2.1	3.6 4.8	mA
V _{icm}	Input Common Mode Voltage Range $T_{amb} = 25^{\circ}C$ $T_{min.} \le T_{amb} \le T_{max.}$	±12 ±12			V
CMR	Common Mode Rejection Ratio ($R_S \le 10k\Omega$) $T_{amb} = 25^{\circ}C$ $T_{min.} \le T_{amb} \le T_{max.}$	70 70	110		dB
los	Output Short-circuit Current T _{amb} = 25°C	10	25	35	mA
± V _{opp}	$ \begin{array}{ll} \text{Output Voltage Swing} \\ T_{amb} = 25^{\circ}C & R_{L} = 10k\Omega \\ R_{L} = 2k\Omega \\ T_{min.} \leq T_{amb} \leq T_{max}. & R_{L} = 10k\Omega \\ R_{L} = 2k\Omega \end{array} $	12 10 12 10	13 12		V
SR	Slew Rate ($V_l = \pm 10V$, $R_L = 10k\Omega$, $C_L = 100pF$, $T_{amb} = 25^{\circ}C$, unity Gain)	0.25	0.5		V/µs
t _r	Rise Time ($V_I = \pm 10V$, $R_L = 10k\Omega$, $C_L = 100pF$, $T_{amb} = 25^{\circ}C$, unity Gain)		0.3		μs
K _{OV}	Overshoot (V _I = ± 10 V, R _L = 10 k Ω , C _L = 100 pF, T _{amb} = 25 °C, unity Gain)		5		%
Rı	Input Resistance	0.8	2.5		ΜΩ
GBP	Gain Bandwidth Product (V_I = 10 mV, R_L = 10k Ω , C_L = 100pF, f = 100kHz, T_{amb} = 25°C)	0.7	1.3		MHz
THD	Total Harmonic Distortion (f = 1kHz, A_v = 20dB, R_L = 10k Ω , C_L = 100pF, T_{amb} = 25°C, v_0 = 2 V_{pp})		0.08		%
en	Equivalent Input Noise Voltage (f = 1kHz, $R_s = 100\Omega$)		40		$\frac{\text{nV}}{\sqrt{\text{Hz}}}$
V _{o1} /V _{o2}	Channel Separation		120		√Hz dB

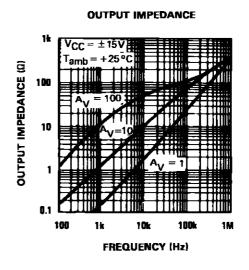












148-08.EPS

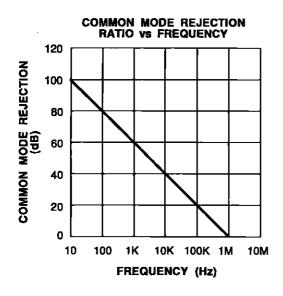
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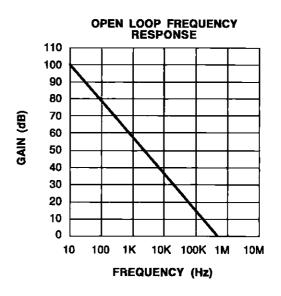
148-03.EPS

148-05.EPS

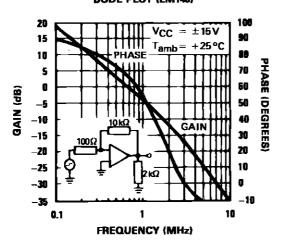
148-04.EPS

148-06.EPS

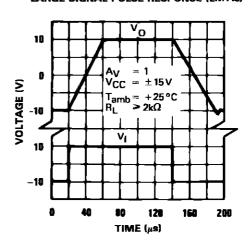




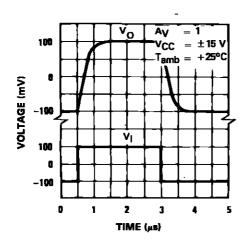
BODE PLOT (LM148)



LARGE SIGNAL PULSE RESPONSE (LM148)



SMALL SIGNAL PULSE RESPONSE (LM148)



GAIN BANDWIDTH PRODUCT VS AMBIENT TEMPERATURE 2.0 1.9 GAIN BANDWIDTH PRODUCT 1.8 1.7 1.6 1.5 1.4 1.3 1.2 1.1 1.0 .9 .8 .7 .6

AMBIENT TEMPERATURE (°C)

148-14.EPS

148-10.EPS

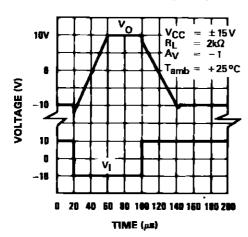
148-12.EPS

148-13.EPS

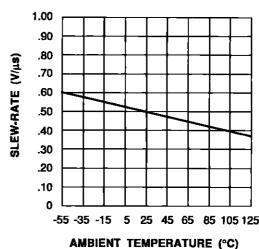
148-09.EPS

148-11.EPS

INVERTING LARGE SIGNAL PULSE RESPONSE (LM148)

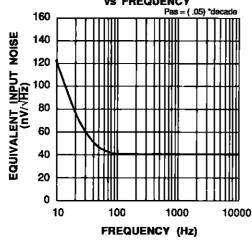


SLEW-RATE VS TEMPERATURE

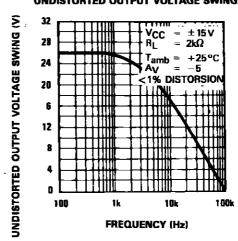


148-15.EPS

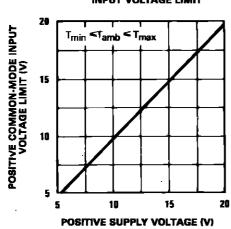
EQUIVALENT INPUT NOISE VS FREQUENCY



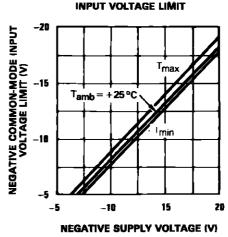
UNDISTORTED OUTPUT VOLTAGE SWING



POSITIVE COMMON-MODE INPUT VOLTAGE LIMIT



NEGATIVE COMMON-MODE



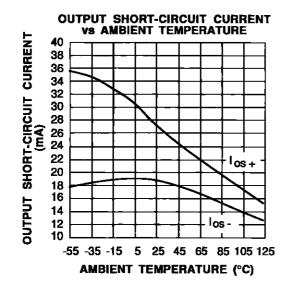
148-19.EPS

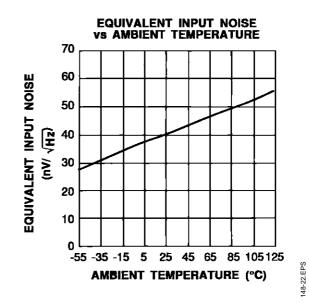
148-17.EPS

148-20.EPS

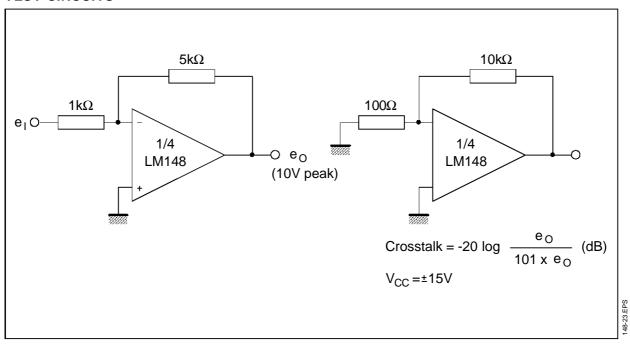
148-16.EPS

148-18.EPS





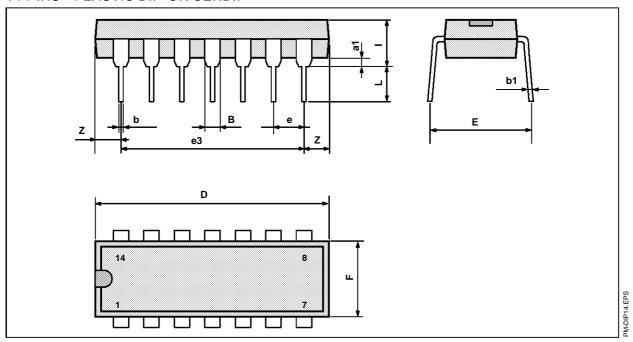
TEST CIRCUITS



148-21.EPS

PACKAGE MECHANICAL DATA

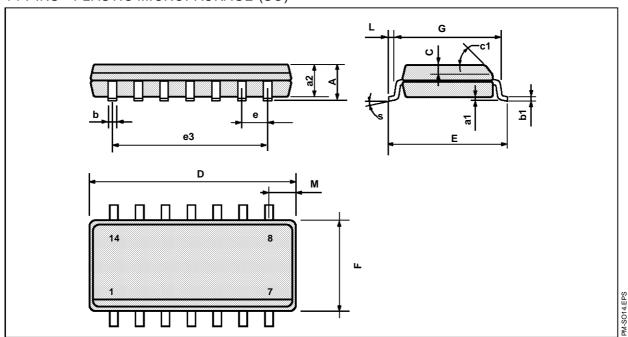
14 PINS - PLASTIC DIP OR CERDIP



Dimensions	Millimeters			Inches		
	Min.	Тур.	Max.	Min.	Тур.	Max.
a1	0.51			0.020		
В	1.39		1.65	0.055		0.065
b		0.5			0.020	
b1		0.25			0.010	
D			20			0.787
Е		8.5			0.335	
е		2.54			0.100	
e3		15.24			0.600	
F			7.1			0.280
i			5.1			0.201
L		3.3			0.130	
Z	1.27		2.54	0.050		0.100

PACKAGE MECHANICAL DATA

14 PINS - PLASTIC MICROPACKAGE (SO)



Dimensions	Millimeters			Inches			
	Min.	Тур.	Max.	Min.	Тур.	Max.	
Α			1.75			0.069	
a1	0.1		0.2	0.004		0.008	
a2			1.6			0.063	
b	0.35		0.46	0.014		0.018	
b1	0.19		0.25	0.007		0.010	
С		0.5			0.020		
c1		45° (typ.)					
D	8.55		8.75	0.336		0.334	
E	5.8		6.2	0.228		0.244	
е		1.27			0.050		
e3		7.62			0.300		
F	3.8		4.0	0.150		0.157	
G	4.6		5.3	0.181		0.208	
L	0.5		1.27	0.020		0.050	
М			0.68			0.027	
S	8° (max.)						

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